

RJH60D0DPM

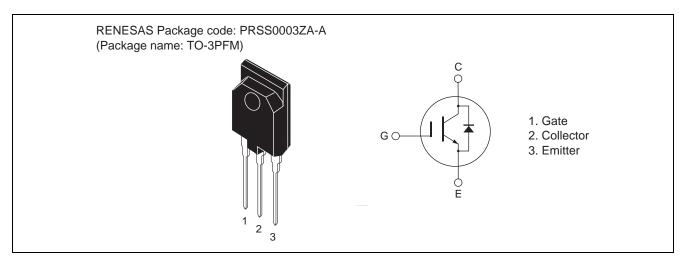
600V - 22A - IGBT Application: Inverter

R07DS0156EJ0300 Rev.3.00 Apr 19, 2012

Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)}=1.6~V$ typ. (at $I_C=22~A,~V_{GE}=15~V,~Ta=25^{\circ}C$)
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching t_f = 70 ns typ. (at V_{CC} = 300 V, V_{GE} = 15 V, I_C = 22 A, Rg = 5 Ω , Ta = 25°C, inductive load)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	Ic	45	А
	Tc = 100°C	Ic	22	А
Collector peak current		ic(peak) Note1	90	А
Collector to emitter diode forward current		I _{DF}	22	Α
Collector to emitter diode forward peak current		i _{DF} (peak) Note1	90	Α
Collector dissipation		P _C Note2	40	W
Junction to case thermal resistance (IGBT)		θj-c Note2	3.13	°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	4.58	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

Electrical Characteristics

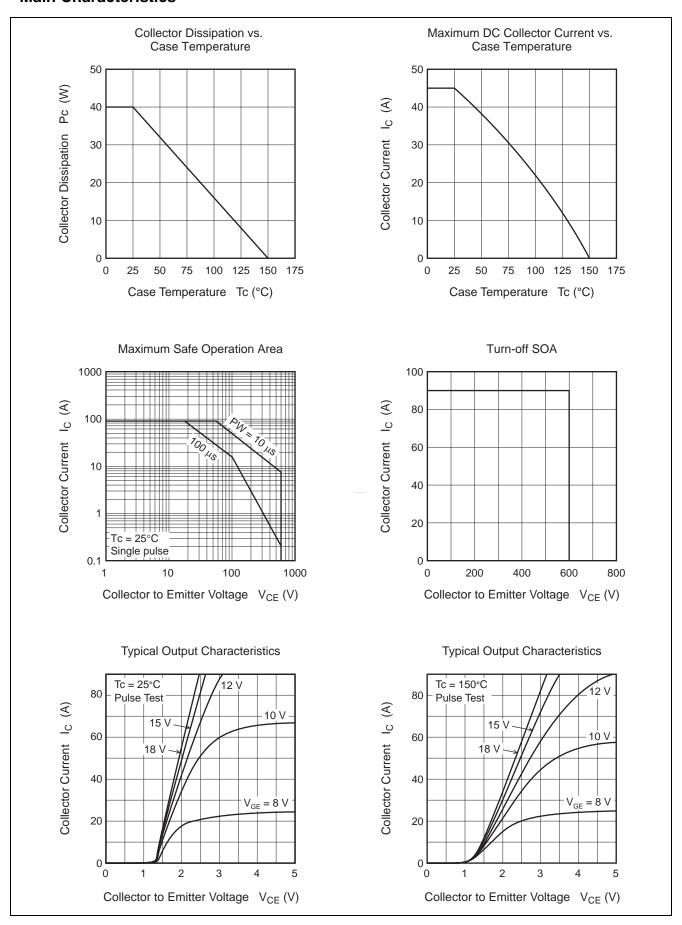
 $(Ta = 25^{\circ}C)$

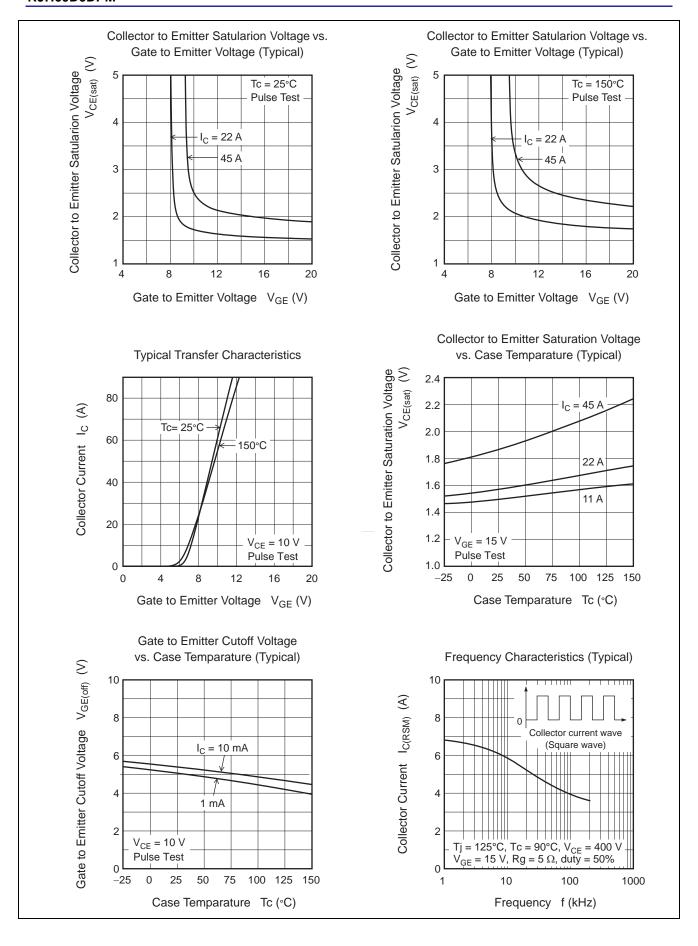
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Collector to emitter breakdown voltage	V _{BR(CES)}	600	_	_	V	$I_C = 10 \mu A, V_{GE} = 0$	
Zero gate voltage collector current / Diode reverse current	I _{CES} / I _R	_	_	5	μА	V _{CE} = 600 V, V _{GE} = 0	
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{\text{GE(off)}}$	4.0	_	6.0	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.6	2.2	V	$I_C = 22 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}	_	2.0	_	V	$I_C = 45 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	1050	_	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	60	_	pF	$V_{GE} = 0$	
Reveres transfer capacitance	Cres	_	28	_	pF	f = 1 MHz	
Total gate charge	Qg	_	46	_	nC	V _{GE} = 15 V V _{CE} = 300 V I _C = 22 A	
Gate to emitter charge	Qge	_	8	_	nC		
Gate to collector charge	Qgc	_	16	_	nC		
Turn-on delay time	t _{d(on)}	_	40	_	ns	$V_{CC} = 300 \text{ V}$ $V_{GE} = 15 \text{ V}$ $I_C = 22 \text{ A}$ $Rg = 5 \Omega$ Inductive load	
Rise time	t _r	_	20	_	ns		
Turn-off delay time	t _{d(off)}	_	80	_	ns		
Fall time	t _f	_	70	_	ns		
Turn-on energy	Eon	_	0.23	_	mJ		
Turn-off energy	E _{off}	_	0.29	_	mJ		
Total switching energy	E _{total}	_	0.52	_	mJ	1	
Short circuit withstand time	t _{sc}	3.0	5.0	_	μS	$V_{CC} \leq 360~V$, V_{GE} = 15 V	
	1	1		T	1	Note 2	
FRD forward voltage	V _F	_	1.4	1.9	V	I _F = 22 A ^{Note3}	
FRD reverse recovery time	t _{rr}	_	100	_	ns	I _F = 22 A	
FRD reverse recovery charge	Ο	_	0.15		пC	di⊧/dt = 100 A/μs	

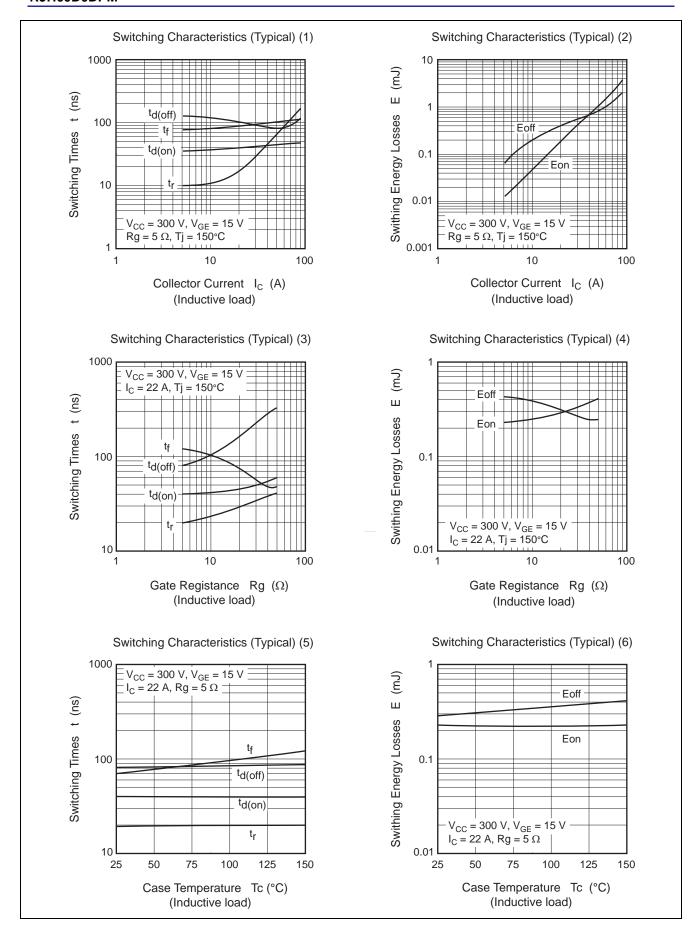
FRD reverse recovery charge 0.15 FRD peak reverse recovery current 4.4

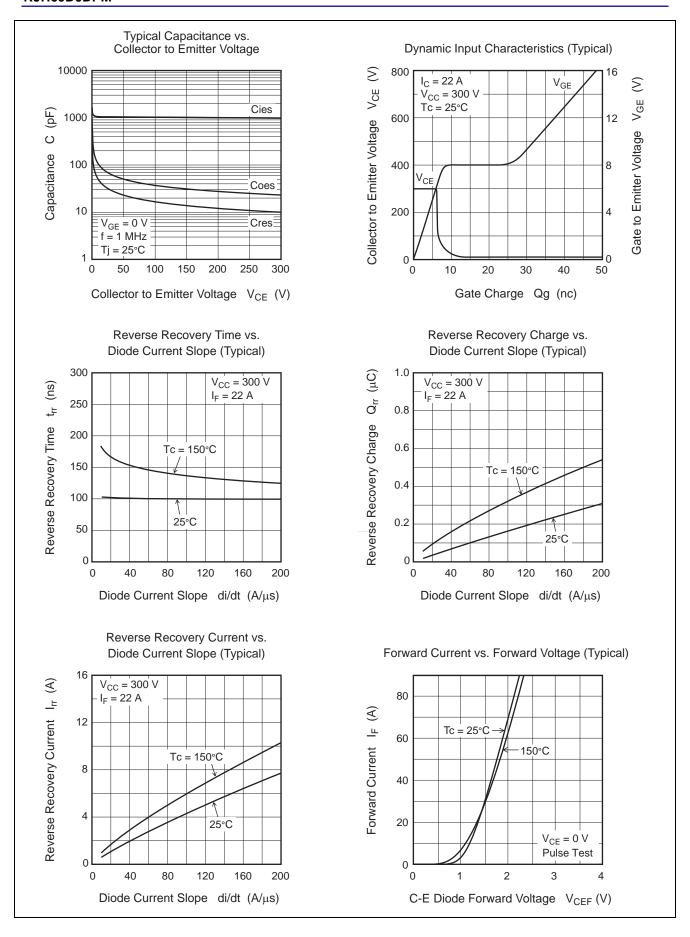
Notes: 3. Pulse test

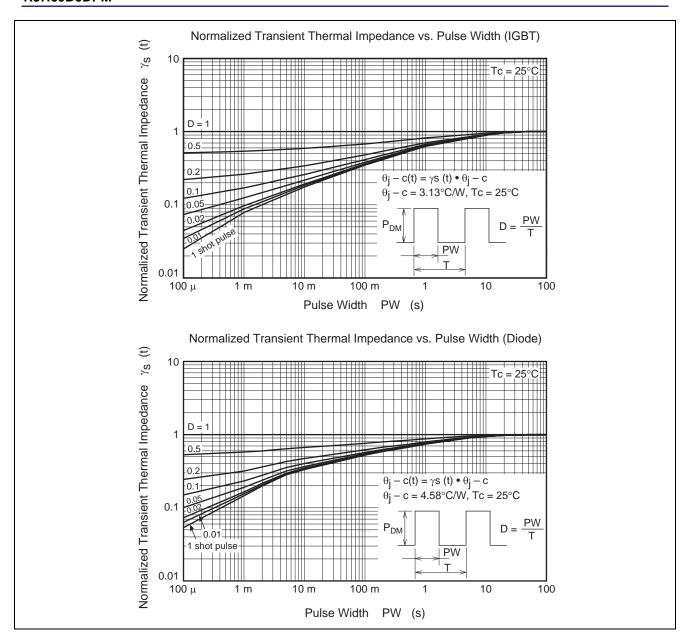
Main Characteristics

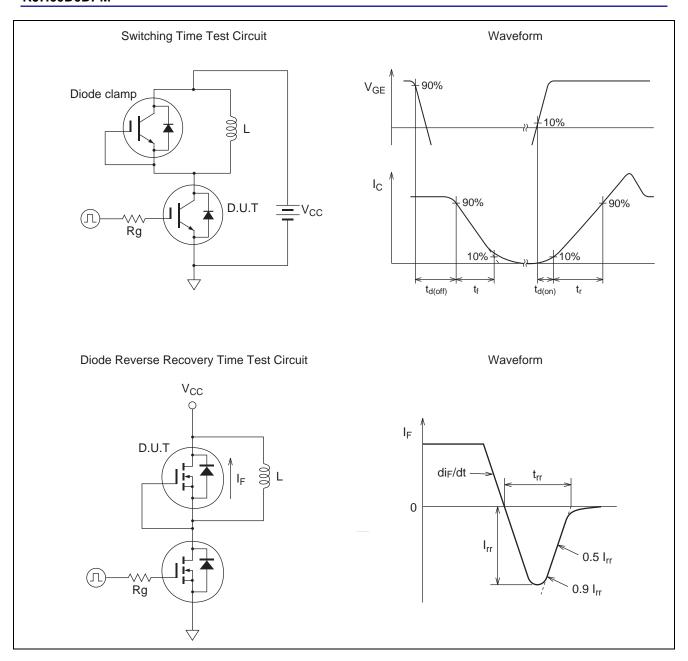




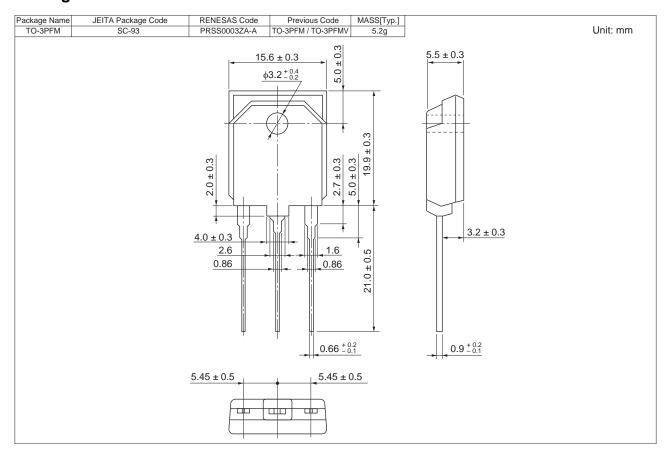








Package Dimension



Ordering Information

Orderable Part No.	Quantity	Shipping Container
RJH60D0DPM-00#T1	360 pcs	Box (Tube)

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